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A bstract

W e use the m ethod of dynam ical mean eld thoery, to study the e ect of K ondo resonance on optical third harm onic generation (T H G) spectra of strongly correlated systems across the m etal-insulator transition. W e nd that T H G signals are proportional to the quasiparticle weight z of the K ondo peak, and are precursors of M ott-H ubbard gap form ation.

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K eywords K ondo resonance; T hird harm onic genration; M etal-insu lator transtion

1 Introduction

O ne of the earliest and m ost in portant trium phs of the D ynam ical mean eld theory (DMFT) [1] was to elucidate the nature of metal-to-insulator transition (MIT) driven by strong electron correlation. It was demonstrated that this transtion is accompanied by a K ondo resonance at the Ferm i surface [2], width of which is proportional to the quasiparticle weight z, and approaches to zero as the M ott insulating side (U ! U_c) is approached from the metallic side. Therefore in nonlinear optical spectra, we expect some signals that vanish in the lim it U ! U_c , as a result of quasiparticle weight z ! 0.

Equivalently one can employ the pressure to tune U_c and hence switch from M ott insulating side to a regime in which such signals arise due to K ondo peak. This is a unique feature of correlated insulators, that has no analogue in band-insulators. In case of band insulators, to generate quasiparticle states in the m id-gap, one m ay need to dope them, while in M ott insulators such m id-gap states can be created by applying pressure to a M ott insulator which is in the onset of M IT .Possible examples would be a class of m aterials known as K ondo insulators [3]. (A typical example of this family is Y BB₁₂ [4]).

2 M ethod of calculation

One of the applications of nonlinear optical materials is the third harmonic generation (THG) [5], that requires materials capable of providing strong enough nonlinear optical signals. To study this process in correlated electronic systems, we have developed the theory of nonlinear optical response in the context of DMFT [6] which is also a suitable theoretical tool to study the elect of K ondo resonance in nonlinear spectra. In d! 1 limit where DMFT becomes exact,

vertex corrections to current operators identically vanish [8] so that the THG succeptibility within DMFT approximation becomes [6]

$${}^{THG}() = \frac{t^4}{6} \frac{Z}{4} \frac{d! d"D(")}{0} \frac{1}{1} \frac{1}{1} \frac{1}{2} \frac{1}{3} \frac{1}{3}; \qquad (1)$$

where j = ! + j R $(! + j) + ij_{I}(! + j)j$ for j = 0;1;2;3, and D $(") = 2 \frac{1}{1} = "^{2}$ is the sem icircular DOS corresponding to the normalized hopping t = 1=2.

In the above formula, (i) the integration over " corresponds to sum mation over interm ediate states in conventional expressions [5] which are usually used for system s with discrete energy levels, and (ii) the matrix element e ects are encoded in (!), real and imaginary part of which have been denoted by $_{\rm R}$ and $_{\rm I}$, respectively. It is very crucial to note that we have used absolute value of the imaginary part of the self-energy. This is indeed a necessary step to transform from tim e-ordered four-current, to fully retarded one[7].

We obtain self-energy by solving the iterated perturbation theory equations of DMFT for the sem i-circular density of states [9]. In DMFT approxim ation, this quantity is purely local.

The critical value of H ubbard U corresponding to sem icircular B ethe lattice is $U_c = 3.35$, above which we are in M ott insulating phase (Fig. 1). As can be seen in Fig. 1, the sharp K ondo resonance state at Ferm i surface in the onset of transition to M ott insulating phase, is characteristic of correlation driven M II.

3 Results

Fig. 2 shows the imaginary part of the THG susceptibility THG () of eq. (1) as a function of incident photon energy for various values of Hubbard U close to M IT.D otted line corresponds to U = 3.5 which is in the M ott insulating phase. The M ott-Hubbard gap is manifested by a region in which Im THG is identically zero. The onset of three-photon absorption as demonstrated earlier [6] corresponds to the frequency where Im THG takes up, and is 1/3 of the M ott-Hubbard gap (E_g).

Three-photon resonances in this form ulation correspond to the peak A in Im ^{THG} around 0.8 (dotted line), while two-photon features appear as a dip B around 1:7 [6]. As can be seen in Fig. 2, except for slight shift in the location of the dip B, the two-photon features are not m uch a ected by m oving to low er values of U in U. U_c region. In contrast, the three-photon features is entirely distorted as we cross the U_c and enter the K ondo regime of U. U_c.

Below the critical value U_c 3:35 the system is in metallic side, with a sharp K ondo peak present at the Ferm i surface [2]. For U = 3:3 (dashed line) just below the critical value, there appear peaky structures below 1. Am ong these structures, weak features denoted by A' and B' in Fig. 2 start to appear in the THG 'gap' region (0 < $< E_g=3$). These features seem to correspond to three-photon and two-photon rosonances between the lower Hubbard band and the K ondo resonance state (schem atically depicted in Fig. 1), as they vanish

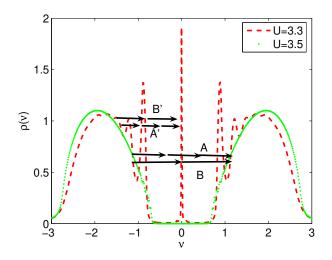


Figure 1: Density of states within DMFT at the onset of transition to insulating state (dashed line) and in the M ott insulating state (dotted line). A and A' represent schem atically the three-photon resonance processes in ^{THG} of Fig. 2. Such three-photon resonances appear as peaks A and A' in Fig. 2, as explained in R ef. [6]. Sim ilarly B and B' in this gure schem atically represent two-photon resonances denoted by B and B' in Fig. 2.

in z ! 0 lim it. Moving further away from M IT, quasiparticle weight z grows s and hence A' and B' features also start to grow proportional to z. To see this proportionality, note that THG in eq. (1) is dominated by D (") e ect, and hence in the lim it z ! 0 one can replace the K ondo peak with a sharp peak of strength z. Then decomposing to partial fractions, each with a single ($_j$ ") denom inator in eq. (1), one can see that j photon features for j = 1;2;3 will be proportional to z.

Implication of this observation for K ondo insulators is that, an external pressures on the order of a fraction of G P a can lead to instability in the functioning of optical devices built on them by lling in the gap and hence reducing the contrast of the output signal.

4 A cknow ledgem ents

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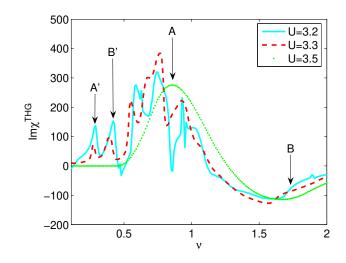


Figure 2: Im aginary part of ^{THG} across the M ott m etal-to-insulator transition. Critical value of U is 3:35. Solid line corresponds to U = 3:2, dashed line corresponds to U = 3:3, and dotted line corresponds to U = 3:5, which is in the M ott insulating side of M IT transition. The onset of three-photon absorption for U = 3:5 is where in aginary part of ^{THG} starts to become non-zero (around 0:5).

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